CMOS Digital Integrated Circuits Silicon Monolithic

# 74VHCV574FT

## 1. Functional Description

Octal Schmitt D-Type Flip-Flop with 3-State Outputs

#### 2. General

The 74VHCV574FT is advanced high speed CMOS OCTAL FLIP-FLOP with 3-STATE OUTPUT fabricated with silicon gate CMOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This 8-bit D-type flip-flop is controlled by a clock input (CK) and an output enable input ( $\overline{\text{OE}}$ ).

When the  $\overline{OE}$  input is high, the eight outputs are in a high impedance state.

Input pin have hysteresis between the positive-going and negative-going thresholds. Thus the 74VHCV574FT is capable of squaring up transitions of slowly changing input signals and provides an improved noise immunity.

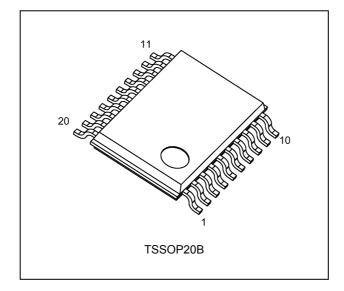
Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output (Note) pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, etc.

Note: Output in off-state.

#### 3. Features

- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range:  $T_{opr} = -40$  to 125 °C
- (3) High speed:  $f_{MAX}$  = 180 MHz (typ.) at  $V_{CC}$  = 5.0 V
- (4) Low power dissipation:  $I_{CC} = 2.0 \ \mu A \ (max)$  at  $T_a = 25^{\circ}C$
- (5) Wide operating voltage range:  $V_{CC(opr)} = 1.8 \text{ V to } 5.5 \text{ V}$
- (6) Output current:  $|I_{OH}|/I_{OL} = 16 \text{ mA (min)}(V_{CC} = 4.5 \text{ V})$
- (7) Power-down protection is provided on all inputs and outputs.
- (8) Pin and function compatible with the 74 series (74AC/HC/AHC/LV etc.) 574 type.
- Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

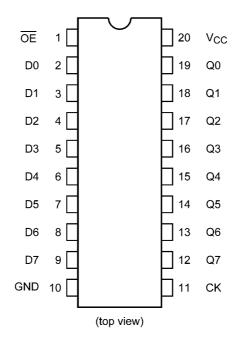
#### 4. Packaging



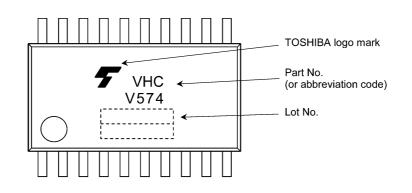
Start of commercial production 2014-07 2016-08-05 Rev.2.0

# 5. Pin Assignment

TOSHIBA



## 6. Marking



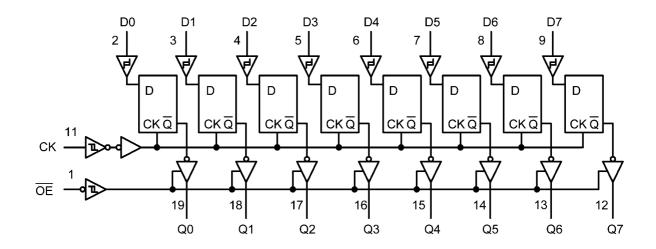
## 7. Truth Table

	Inputs	puts Outr		
ŌĒ	СК	D	Output	
н	Х	Х	Z	
L		Х	Qn	
L		L	L	
L		Н	Н	

- X: Don't care
- Z: High impedance
- Qn: No change

# TOSHIBA

# 8. System Diagram



#### 9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		-0.5 to 7.0	V
Input voltage	V <sub>IN</sub>		-0.5 to 7.0	V
Output voltage	V <sub>OUT</sub>	(Note 1)	-0.5 to 7.0	V
		(Note 2)	-0.5 to V <sub>CC</sub> + 0.5	
Input diode current	I <sub>IK</sub>		-50	mA
Output diode current	Ι <sub>ΟΚ</sub>	(Note 3)	±50	mA
Output current	I <sub>OUT</sub>		±50	mA
Power dissipation	PD	(Note 4)	180	mW
V <sub>CC</sub> /ground current	I <sub>CC</sub> /I <sub>GND</sub>		±100	mA
Storage temperature	T <sub>stg</sub>		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Output in OFF state.

Note 2: High (H) or Low (L) state.  $I_{OUT}$  absolute maximum rating must be observed.

Note 3:  $V_{OUT}$  < GND,  $V_{OUT}$  >  $V_{CC}$ 

Note 4: 180 mW in the range of  $T_a = -40$  to 85 °C. From  $T_a = 85$  to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

## 10. Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>	—		1.8 to 5.5	V
Input voltage	V <sub>IN</sub>	—		0 to 5.5	V
Output voltage	V <sub>OUT</sub>	—	(Note 1)	0 to 5.5	V
			(Note 2)	0 to V <sub>CC</sub>	
Operating temperature	T <sub>opr</sub>	—		-40 to 125	°C
Input rise and fall times	dt/dv	$V_{CC}$ = 3.3 $\pm$ 0.3 V		0 to 20	ms/V
		$V_{CC}$ = 5 $\pm$ 0.5 V		0 to 1	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

Note 1: Output in OFF state.

Note 2: High (H) or Low (L) state.

# TOSHIBA

# **11. Electrical Characteristics**

# 11.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Test Conditio	on	V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
Positive threshold voltage	V <sub>P</sub>	_	1.8	_	_	1.65	V	
			2.3	_	_	1.85	1	
				3.0	_	_	2.20	
				4.5	_	_	3.15	1
				5.5	_	_	3.85	
Negative threshold voltage	V <sub>N</sub>	—		1.8	0.15	_	_	V
				2.3	0.45	_	_	1
				3.0	0.90	_	_	
				4.5	1.35	_	_	
				5.5	1.65	_	_	1
Hysteresis voltage	V <sub>H</sub>	_		1.8	0.15	_	1.05	V
				2.3	0.20	_	1.10	
				3.0	0.30	_	1.20	1
				4.5	0.40	_	1.40	
				5.5	0.50	_	1.60	
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	1.8	1.7	1.8	_	V
				3.0	2.9	3.0	_	
				4.5	4.4	4.5	_	
			I <sub>OH</sub> = -8 mA	3.0	2.58	_	_	
			I <sub>OH</sub> = -16 mA	4.5	3.94	—		
Low-level output voltage	V <sub>OL</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I <sub>OL</sub> = 50 μA	1.8	_	0.0	0.1	<ul> <li></li> </ul>
				3.0	_	0.0	0.1	
				4.5	_	0.0	0.1	
			I <sub>OL</sub> = 8 mA	3.0	_	_	0.36	
			I <sub>OL</sub> = 16 mA	4.5	—	—	0.44	
3-state output OFF-state leakage current	I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = 0 to 5.5 V		1.8 to 5.5	—	—	±0.5	μA
Power-OFF leakage current	I <sub>OFF</sub>	$V_{IN}/V_{OUT} = 5.5 V$		0	_	_	0.5	μA
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	—	_	±0.1	μA
Quiescent supply current	I <sub>CC</sub>	$V_{IN} = V_{CC}$ or GND		5.5	—	—	2.0	μA

# 11.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Test Conditior	ı	V <sub>CC</sub> (V)	Min	Max	Unit
Positive threshold voltage	VP	—		1.8	_	1.65	V
				2.3	_	1.85	
				3.0	_	2.20	
				4.5	_	3.15	
				5.5	—	3.85	
Negative threshold voltage	V <sub>N</sub>	—		1.8	0.15	—	V
				2.3	0.45	—	
				3.0	0.90	—	
				4.5	1.35	_	
				5.5	1.65	_	
Hysteresis voltage	V <sub>H</sub>	—		1.8	0.15	1.05	V
				2.3	0.20	1.10	
				3.0	0.30	1.20	
				4.5	0.40	1.40	
				5.5	0.50	1.60	1
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I <sub>OH</sub> = -50 μA	1.8	1.7	_	V
				3.0	2.9	_	
				4.5	4.4	_	
			I <sub>OH</sub> = -8 mA	3.0	2.48	—	
			I <sub>OH</sub> = -16 mA	4.5	3.80	—	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	1.8	_	0.1	V
				3.0	_	0.1	
				4.5	_	0.1	
			I <sub>OL</sub> = 8 mA	3.0	_	0.44	
			I <sub>OL</sub> = 16 mA	4.5	_	0.55	
3-state output OFF-state leakage current	I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = 0 to 5.5 V		1.8 to 5.5	—	±5.0	μΑ
Power-OFF leakage current	I <sub>OFF</sub>	$V_{IN}/V_{OUT}$ = 5.5 V		0	—	5.0	μA
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	—	±1.0	μA
Quiescent supply current	I <sub>CC</sub>	$V_{IN} = V_{CC}$ or GND		5.5	_	20.0	μA

# 11.3. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C)

Characteristics	Symbol	Test Conditior	ı	V <sub>CC</sub> (V)	Min	Max	Unit
Positive threshold voltage	V <sub>P</sub>	—	—			1.65	V
				2.3	_	1.85	
				3.0	_	2.20	
				4.5	_	3.15	
				5.5	_	3.85	
Negative threshold voltage	V <sub>N</sub>	—		1.8	0.15	—	V
				2.3	0.45	—	
				3.0	0.90	—	
				4.5	1.35	_	
				5.5	1.65	—	
Hysteresis voltage	V <sub>H</sub>	—		1.8	0.15	1.05	V
				2.3	0.20	1.10	
				3.0	0.30	1.20	
				4.5	0.40	1.40	
				5.5	0.50	1.60	
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I <sub>OH</sub> = -50 μA	1.8	1.7	—	V
				3.0	2.9	—	
				4.5	4.4	—	
			I <sub>OH</sub> = -8 mA	3.0	2.40	—	
			I <sub>OH</sub> = -16 mA	4.5	3.70	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	1.8	_	0.1	V
				3.0	_	0.1	
				4.5	_	0.1	
			I <sub>OL</sub> = 8 mA	3.0	_	0.55	
			I <sub>OL</sub> = 16 mA	4.5	_	0.65	
3-state output OFF-state leakage current	I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = 0 to 5.5 V		1.8 to 5.5	_	±20.0	μA
Power-OFF leakage current	I <sub>OFF</sub>	V <sub>IN</sub> /V <sub>OUT</sub> = 5.5 V		0		20.0	μA
Input leakage current	l <sub>iN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5		±2.0	μΑ
Quiescent supply current	I <sub>CC</sub>	$V_{IN} = V_{CC}$ or GND		5.5	_	40.0	μA

## 11.4. Timing Requirements (Unless otherwise specified, $T_a = 25^{\circ}C$ , Input: $t_r = t_f = 3 \text{ ns}$ )

Characteristics	Symbol	V <sub>CC</sub> (V)	Limit	Unit
Minimum pulse width (CK)	$t_{w(L)}, t_{w(H)}$	$2.5\pm0.2$	7.0	ns
		$3.3\pm0.3$	5.0	1
		5.0 ± 0.5	5.0	]
Minimum setup time	ts	$2.5\pm0.2$	5.5	ns
		$3.3\pm0.3$	3.5	
		5.0 ± 0.5	3.5	
Minimum hold time	t <sub>h</sub>	$2.5\pm0.2$	2.0	ns
		$3.3\pm0.3$	1.5	]
		5.0 ± 0.5	1.5	]

# 11.5. Timing Requirements (Unless otherwise specified, $T_a = -40$ to 85°C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	V <sub>CC</sub> (V)	Limit	Unit
Minimum pulse width (CK)	t <sub>w(L)</sub> ,t <sub>w(H)</sub>	$2.5\pm0.2$	7.0	ns
		$3.3\pm0.3$	5.0	
		5.0 ± 0.5	5.0	
Minimum setup time	t <sub>S</sub>	$2.5\pm0.2$	5.5	ns
		$3.3\pm0.3$	3.5	
		5.0 ± 0.5	3.5	
Minimum hold time	t <sub>h</sub>	$2.5\pm0.2$	2.0	ns
		$3.3\pm0.3$	1.5	
		5.0 ± 0.5	1.5	

# 11.6. Timing Requirements (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	V <sub>CC</sub> (V)	Limit	Unit
Minimum pulse width (CK)	$t_{w(L)}, t_{w(H)}$	$2.5\pm0.2$	7.0	ns
		$3.3\pm0.3$	5.0	
		$5.0\pm0.5$	5.0	
Minimum setup time	t <sub>s</sub>	$2.5\pm0.2$	7.0	ns
		$3.3\pm0.3$	4.5	
		$5.0\pm0.5$	4.0	
Minimum hold time	t <sub>h</sub>	$2.5\pm0.2$	2.0	ns
		$3.3\pm0.3$	1.5	
		$5.0\pm0.5$	1.5	

## 11.7. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		—	$2.5\pm0.2$	15	_	9.1	16.6	ns
(CK-Q)					50	_	11.9	19.6	
				$\textbf{3.3}\pm\textbf{0.3}$	15	_	6.7	13.2	
					50	_	8.9	16.7	
				$5.0\pm0.5$	15	_	5.0	8.6	
					50	—	6.7	10.6	
3-state output enable time	t <sub>PZL</sub> ,t <sub>PZH</sub>		$R_L = 1 k\Omega$	$\textbf{2.5}\pm\textbf{0.2}$	15	—	7.6	16.1	ns
					50	—	10.7	19.0	
				$\textbf{3.3}\pm\textbf{0.3}$	15	_	5.7	12.8	
					50	_	8.1	16.3	
				$5.0\pm0.5$	15	_	4.2	9.0	
					50	_	6.1	11.0	
3-state output disable time	t <sub>PLZ</sub> ,t <sub>PHZ</sub>		$R_L = 1 k\Omega$	$2.5\pm0.2$	50	_	13.6	17.5	ns
				$\textbf{3.3}\pm\textbf{0.3}$	50	_	10.5	15.0	
				$5.0\pm0.5$	50	_	8.2	10.1	
Maximum clock frequency	f <sub>MAX</sub>		_	$2.5\pm0.2$	15	60	95	_	MHz
					50	50	75	_	
				$\textbf{3.3}\pm\textbf{0.3}$	15	80	135	_	
					50	55	100	_	
				$5.0\pm0.5$	15	130	180	_	
					50	85	135	_	
Output skew	t <sub>osLH</sub> ,t <sub>osHL</sub>	(Note 1)	_	$2.5\pm0.2$	50	_		2.0	ns
				$\textbf{3.3}\pm\textbf{0.3}$	50			1.5	
				$5.0\pm0.5$	50	_	_	1.0	ns
Input capacitance	C <sub>IN</sub>		_			_	4	10	pF
Output capacitance	C <sub>OUT</sub>		—			_	6	_	pF
Power dissipation capacitance	C <sub>PD</sub>	(Note 2)	_			_	26	—	pF

Note 1: Parameter guaranteed by design. ( $t_{osLH} = |t_{PLH}m-t_{PLH}n|$ ,  $t_{osHL} = |t_{PHL}m-t_{PHL}n|$ )

Note 2: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8$  (per latch)

And the total  $C_{\text{PD}}$  when n pcs. of latch operate can be gained by the following equation.

 $C_{PD}$  (total) = 14 + 12 × n

# 11.8. AC Characteristics (Upless otherwise specified $T_{r} = -40$ to 8

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		—	$2.5\pm0.2$	15	1.0	20.0	ns
(CK-Q)					50	1.0	23.0	
				$\textbf{3.3}\pm\textbf{0.3}$	15	1.0	15.5	
					50	1.0	19.0	
				$5.0\pm0.5$	15	1.0	10.0	
					50	1.0	12.0	
3-state output enable time	t <sub>PZL</sub> ,t <sub>PZH</sub>		R <sub>L</sub> = 1 kΩ	$\textbf{2.5}\pm\textbf{0.2}$	15	1.0	19.0	ns
					50	1.0	22.0	
				$3.3\pm0.3$	15	1.0	15.0	
					50	1.0	18.5	
				$5.0\pm0.5$	15	1.0	10.5	
					50	1.0	12.5	
3-state output disable time	t <sub>PLZ</sub> ,t <sub>PHZ</sub>		R <sub>L</sub> = 1 kΩ	$\textbf{2.5}\pm\textbf{0.2}$	50	1.0	20.0	ns
				$\textbf{3.3}\pm\textbf{0.3}$	50	1.0	17.0	
				$5.0\pm0.5$	50	1.0	11.5	
Maximum clock frequency	f <sub>MAX</sub>		—	$2.5\pm0.2$	15	50	—	MHz
					50	40	—	
				$\textbf{3.3}\pm\textbf{0.3}$	15	65	—	
					50	45	—	
				$5.0\pm0.5$	15	110	—	
					50	75	_	
Output skew	t <sub>osLH</sub> ,t <sub>osHL</sub>	(Note 1)		$2.5\pm0.2$	50	_	2.0	ns
				$3.3\pm0.3$	50	_	1.5	
				$5.0\pm0.5$	50	_	1.0	ns
Input capacitance	C <sub>IN</sub>					_	10	pF

Note 1: Parameter guaranteed by design.  $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$ 

# 11.9. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	$C_L (pF)$	Min	Max	Unit
Propagation delay time (CK-Q)	t <sub>PLH</sub> ,t <sub>PHL</sub>		—	$2.5\pm0.2$	15	1.0	22.5	ns
					50	1.0	25.5	
				$\textbf{3.3}\pm\textbf{0.3}$	15	1.0	17.5	
					50	1.0	21.0	
				$5.0\pm0.5$	15	1.0	11.5	
					50	1.0	13.5	
3-state output enable time	t <sub>PZL</sub> ,t <sub>PZH</sub>		$R_L = 1 k\Omega$	$2.5\pm0.2$	15	1.0	21.0	ns
					50	1.0	24.0	
				$3.3\pm0.3$	15	1.0	17.0	
					50	1.0	20.5	
				$5.0\pm0.5$	15	1.0	12.0	
					50	1.0	14.0	
3-state output disable time	t <sub>PLZ</sub> ,t <sub>PHZ</sub>		$R_L = 1 k\Omega$	$2.5\pm0.2$	50	1.0	22.0	ns
				$\textbf{3.3}\pm\textbf{0.3}$	50	1.0	19.0	
				$5.0\pm0.5$	50	1.0	13.0	
Maximum clock frequency	f <sub>MAX</sub>		—	$2.5\pm0.2$	15	40	—	MHz
					50	30	—	
				$\textbf{3.3}\pm\textbf{0.3}$	15	60	—	
					50	40	—	
				$5.0\pm0.5$	15	100	—	
					50	65	—	
Output skew	t <sub>osLH</sub> ,t <sub>osHL</sub>	(Note 1)	_	$2.5\pm0.2$	50	_	2.0	ns
				$\textbf{3.3}\pm\textbf{0.3}$	50	_	1.5	
				$5.0\pm0.5$	50	_	1.0	
Input capacitance	C <sub>IN</sub>		_			_	10	pF

Note 1: Parameter guaranteed by design. ( $t_{osLH} = |t_{PLH}m-t_{PLH}n|$ ,  $t_{osHL} = |t_{PHL}m-t_{PHL}n|$ )

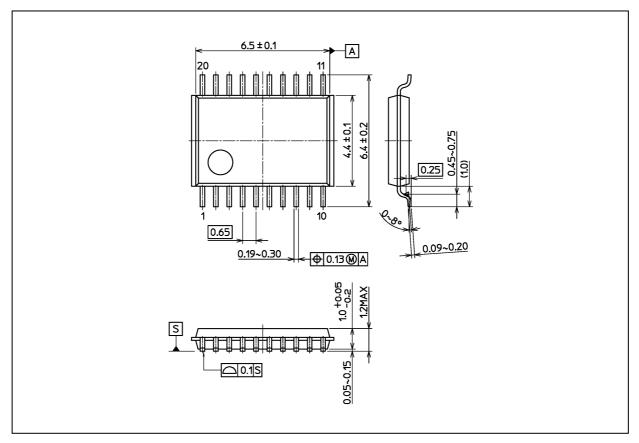
# 11.10. Noise Characteristics (Unless otherwise specified, $T_a = 25^{\circ}$ C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Max	Unit
Quiet output maximum dynamic $V_{OL}$	V <sub>OLP</sub>	C <sub>L</sub> = 50 pF	3.3	0.4	_	V
			5.0	0.8	_	
Quiet output minimum dynamic V <sub>OL</sub>	V <sub>OLV</sub>	C <sub>L</sub> = 50 pF	3.3	-0.1		V
			5.0	-0.4	_	
Minimum high-level dynamic input voltage	V <sub>IHD</sub>	C <sub>L</sub> = 50 pF	5.0	_	3.5	V
Maximum low-level dynamic input voltage		C <sub>L</sub> = 50 pF	5.0	_	1.5	V



## Package Dimensions

Unit: mm



Weight: 0.071 g (typ.)

	Package Name(s)	
Nickname: TSSOP20B		

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